

Description

The CXG1214UR is a 3P3T (Triple Pole Triple Throw) switch and suitable for wireless communication systems, for example, W-CDMA handsets.

This IC has on-chip logic for operation with 3 CMOS control inputs.

Low insertion loss and on-chip logic circuit are realized by the Sony JPHEMT process.

(Applications: Antenna switch for cellular handsets, triple band W-CDMA)

Features

- ◆ Low insertion loss: 0.25dB@900MHz
- ◆ 3 CMOS compatible control line

Package

Small package size: 20-pin UQFN

Structure

GaAs JPHEMT MMIC

Absolute Maximum Ratings

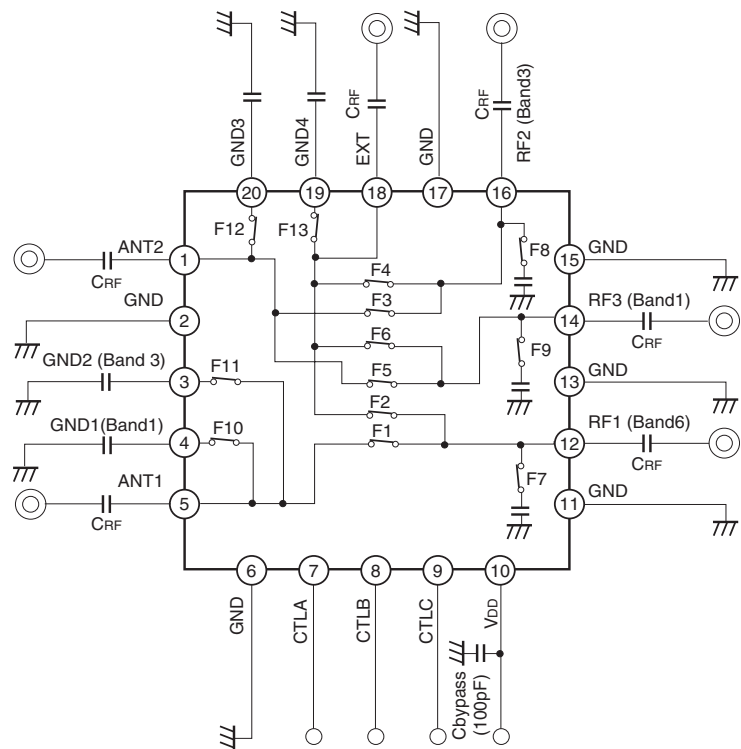
(Ta = 25°C)

◆ Bias voltage	V _{DD}	7	V
◆ Control voltage	V _{ctl}	5	V
◆ Operating temperature	T _{opr}	–35 to +85	°C
◆ Storage temperature	T _{stg}	–65 to +150	°C

This IC is ESD sensitive device. Special handling precautions are required.

Sony reserves the right to change products and specifications without prior notice. This information does not convey any license by any implication or otherwise under any patents or other right. Application circuits shown, if any, are typical examples illustrating the operation of the devices. Sony cannot assume responsibility for any problems arising out of the use of these circuits.

Block Diagram and Recommended Circuit



When using this IC, the following external components should be used:
CRF: This capacitor is used for RF decoupling and must be used for all applications.
Cbypass: This capacitor is used for DC line filtering.

Truth Table

State	CTLA	CTLB	CTLC	ON path	F1	F2	F3	F4	F5	F6	F7	F8	F9	F10	F11	F12	F13
1	H	L	H	RF1 – ANT1	ON	OFF	OFF	OFF	OFF	OFF	OFF	ON	ON	OFF	OFF	ON	ON
2	L	H	H	RF2 – ANT2	OFF	OFF	ON	OFF	OFF	OFF	ON	OFF	ON	OFF	ON	OFF	ON
3	L	L	H	RF3 – ANT2	OFF	OFF	OFF	OFF	ON	OFF	ON	ON	OFF	ON	OFF	OFF	ON
4	H	L	L	RF1 – EXT	OFF	ON	OFF	OFF	OFF	OFF	OFF	ON	ON	OFF	ON	ON	OFF
5	L	H	L	RF2 – EXT	OFF	OFF	OFF	ON	OFF	OFF	ON	OFF	ON	OFF	ON	ON	OFF
6	L	L	L	RF3 – EXT	OFF	OFF	OFF	OFF	OFF	ON	ON	ON	OFF	ON	ON	ON	OFF

DC Bias Conditions

(Ta = 25°C)

Item	Min.	Typ.	Max.	Unit
Vctl (H)	2.2	2.85	3.2	V
Vctl (L)	0	—	0.4	V
VDD	2.6	2.85	3.2	V

Electrical Characteristics

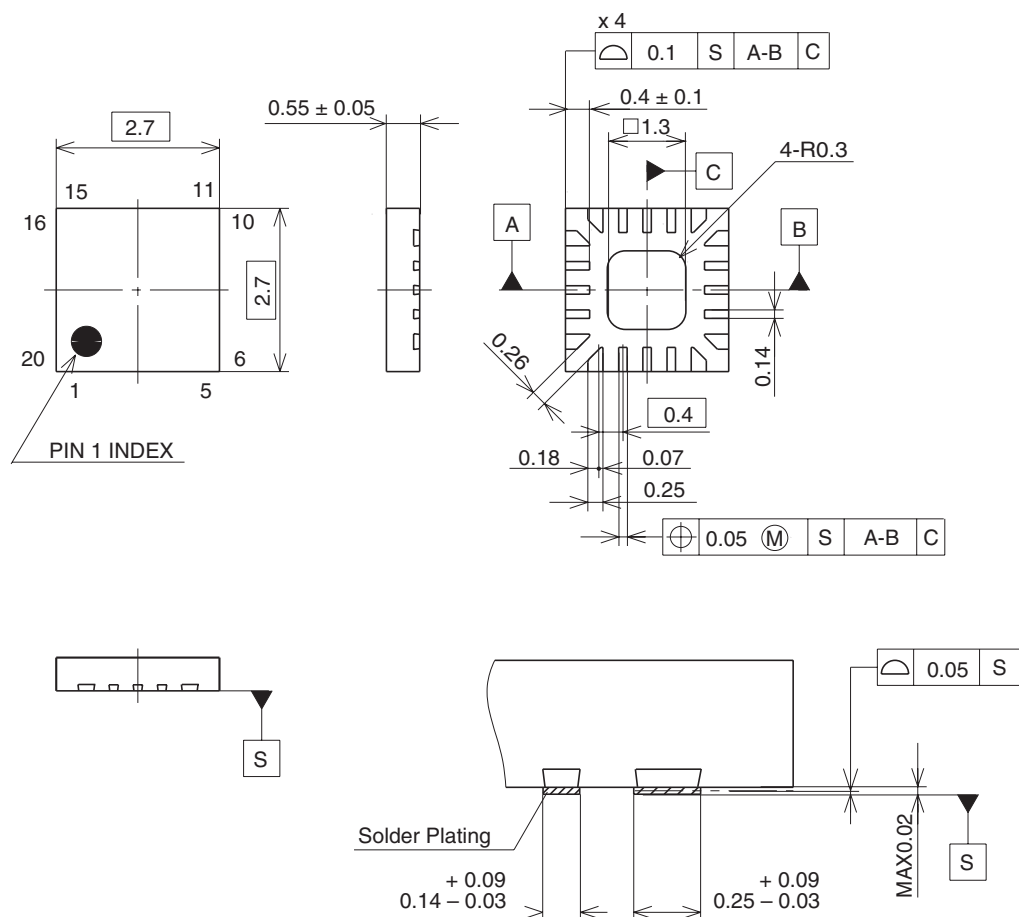
(Ta = 25°C)

Item	Symbol	State	Path	Condition	Min.	Typ.	Max.	Unit
Insertion loss	IL	1 2 3	RF1 – ANT1 RF2 – ANT2 RF3 – ANT2	830 to 885MHz		0.35	0.50	dB
				1749.9 to 1880MHz		0.45	0.65	dB
				1920 to 1980MHz		0.47	0.67	dB
				2110 to 2170MHz		0.50	0.75	dB
		4 5 6	RF1 – EXT RF2 – EXT RF3 – EXT	830 to 885MHz		0.40	0.55	dB
				1749.9 to 1880MHz		0.53	0.73	dB
				1920 to 1980MHz		0.55	0.75	dB
				2110 to 2170MHz		0.60	0.85	dB
Isolation	ISO	4 5 6	RF1 – ANT1 RF2 – ANT2 RF3 – ANT2	830 to 885MHz	25	35		dB
				1749.9 to 1880MHz	20	30		dB
				1920 to 2170MHz	20	30		dB
		1	RF1 – EXT	830 to 885MHz	25	35		dB
				1749.9 to 1880MHz	20	30		dB
				1920 to 2170MHz	20	30		dB
		2	RF2 – EXT	830 to 885MHz	20	27		dB
				1749.9 to 1880MHz	17	23		dB
				1920 to 2170MHz	15	21		dB
		3	RF3 – EXT	830 to 885MHz	20	30		dB
				1749.9 to 1880MHz	20	27		dB
				1920 to 2170MHz	19	25		dB
VSWR	VSWR			50Ω		1.2		
Switching speed	TSW					5	10	
1dB compression input power	P1dB			V _{DD} = 2.85V		32		dBm
ACLR	ACLR1			±5MHz, 3.84MHz BW*1			–50	dBc
	ACLR2			±10MHz, 3.84MHz BW*1			–55	dBc
Harmonics	2fo			*1			–45	dBm
	3fo			*1			–45	dBm
Bias current	I _{dd}			V _{DD} = 2.85V		200	330	μA
Control current	I _{ctl}			V _{ctl} (H) = 2.85V		30	50	μA

*1 Pin = 25dBm, 0/2.85V control, V_{DD} = 2.85V, 830 to 840MHz, 1749.9 to 1785MHz, 1920 to 1980MHz, Measurement system noise level : ACLR(±5MHz) <–60dBc, (±10MHz) <–65dBc, 2nd Harmonics <–75dBm, 3rd Harmonics <–75dBm

(Unit: mm)

20PIN UQFN (PLASTIC)



TERMINAL SECTION

Note:Cutting burr of lead are 0.05mm MAX.

SONY CODE	UQFN-20P-01
EIAJ CODE	_____
JEDEC CODE	_____

PACKAGE STRUCTURE

PACKAGE MATERIAL	EPOXY RESIN
LEAD TREATMENT	SOLDER PLATING
LEAD MATERIAL	COPPER ALLOY
PACKAGE MASS	0.02g

LEAD PLATING SPECIFICATIONS

ITEM	SPEC.
LEAD MATERIAL	COPPER ALLOY
SOLDER COMPOSITION	Sn-Bi Bi:1-4wt%
PLATING THICKNESS	5-18μm